

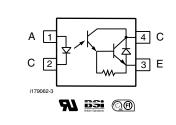
RoHS

COMPLIANT

Vishay Semiconductors

Optocoupler, Photodarlington Output, High Gain, 300 V BV_{CEO}





DESCRIPTION

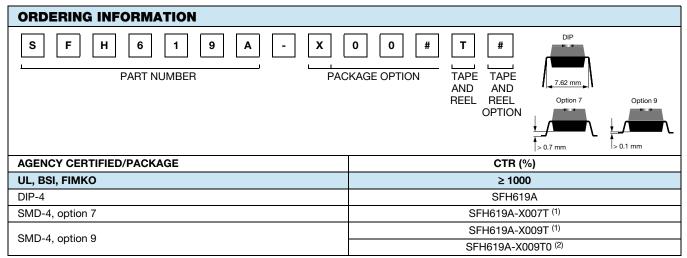
The SFH619A is optically coupled isolators with a gallium arsenide infrared LED and a silicon photodarlington sensor. Switching can be achieved while maintaining a high degree of isolation between driving and load circuits. These optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

FEATURES

- High collector emitter voltage, V_{CEO} = 300 V
- High isolation test voltage: 5300 V_{RMS}
- Standard plastic DIP-4 package
- Compatible with Toshiba TLP627
- Compliant to RoHS Directive to 2002/95/EC and in accordance WEEE 2002/96/EC

AGENCY APPROVALS

- UL file no. E52744 system code H
- BSI IEC 60950; IEC 60065
- FIMKO



Note

- Additional options may be possible, please contact sales office.
- ⁽¹⁾ Also available in tubes; do not put T on the end.
- $^{(2)}\,$ Option with 90° rotation.

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
Peak reverse voltage		V _{RM}	6	V				
Forward continuous current		I _F	60	mA				
Derate linearly from 25 °C			1.33	mW/°C				
Power dissipation		P _{diss}	100	mW				
OUTPUT		<u>.</u>						
Collector emitter breakdown voltage		BV _{CEO}	300	V				
Emitter collector breakdown voltage		BV _{ECO}	0.3	V				
Collector (load) current		Ι _C	125	mA				
Derate linearly from 25 °C			2	mW/°C				
Power dissipation		P _{diss}	150	mW				

Document Number: 83674 Rev. 1.7, 15-Feb-11 For technical questions, contact: optocoupler.answers@vishay.com

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
COUPLER							
Derate linearly from 25 °C			3.33	mW/°C			
Total power dissipation		P _{tot}	250	mW			
Isolation test voltage between emitter and detector	t = 1 s	V _{ISO}	5300	V _{RMS}			
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹²	Ω			
	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹¹	Ω			
Storage temperature		T _{stg}	- 55 to + 150	°C			
Operating temperature		T _{amb}	- 55 to + 100	°C			
Soldering temperature ⁽¹⁾	max. 10 s, dip soldering: distance to seating plane \ge 1.5 mm	T _{sld}	260	°C			

Notes

• Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT							
Forward voltage	I _F = 10 mA	V _F		1.2	1.5	V	
Reverse current	V _R = 6 V	I _R		0.02	10	μA	
Capacitance	$V_R = 0 V$	Co		14		pF	
OUTPUT							
Collector emitter breakdown voltage	I _{CE} = 100 μA	BV _{CEO}	300			V	
Emitter collector breakdown voltage	I _{EC} = 100 μA	BV _{ECO}	0.3			V	
	V _{CE} = 200 V,T _A = 25 °C	I _{CEO}		10	200	nA	
Collector emitter dark current	V _{CE} = 200 V,T _A = 100 °C	I _{CEO}			20	nA	
Collector emitter capacitance	V _{CE} = 0 V, f = 1 MHz	C _{CE}		39		pF	
COUPLER		•					
	I _F = 1 mA, I _C = 10 mA	V _{CEsat}			1	V	
Collector emitter saturation voltage	I _F = 10 mA, I _C = 100 mA	V _{CEsat}	0.3		1.2	V	
Coupling capacitance	V _{I-O} = 0 V, f = 1 MHz	C _C		0.6		pF	

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Coupling transfer ratio	$I_F = 1 \text{ mA}, V_{CE} = 1 \text{ V}$	CTR	1000			%	

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Rise time	V_{CC} = 10 V, I_{C} = 10 mA, R_{L} = 100 Ω	t _r		3.5		μs
nise time	V_{CC} = 10 V, I _F = 16 mA, R _L = 180 Ω	t _r		1		μs
Fall time	V_{CC} = 10 V, I_{C} = 10 mA, R_{L} = 100 Ω	t _f		14.5		μs
r an unie	V_{CC} = 10 V, I _F = 16 mA, R _L = 180 Ω	t _f		20.5		μs
Turn-on time	V_{CC} = 10 V, I_{C} = 10 mA, R_{L} = 100 Ω	t _{on}		4.5		μs
rum-on time	V_{CC} = 10 V, I _F = 16 mA, R _L = 180 Ω	t _{on}		1.5		μs
Turn-off time	V_{CC} = 10 V, I_{C} = 10 mA, R_{L} = 100 Ω	t _{off}		29		μs
	V_{CC} = 10 V, I_F = 16 mA, R_L = 180 Ω	t _{off}		53.5		μs

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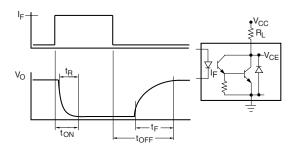
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SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC 68 part 1)				55/100/21			
Comparative tracking index		CTI	175		399		
V _{IOTM}			10000			V	
V _{IORM}			890			V	
P _{SO}					400	mW	
I _{SI}					275	mA	
T _{SI}					175	°C	
Creepage distance	standard DIP-4		7			mm	
Clearance distance	standard DIP-4		7			mm	
Creepage distance	400 mil DIP-4		8			mm	
Clearance distance	400 mil DIP-4		8			mm	
Insulation thickness, reinforced rated	per IEC 60950 2.10.5.1		0.4			mm	

Note

As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)



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Fig. 1 - Switching Waveform and Switching Schematic

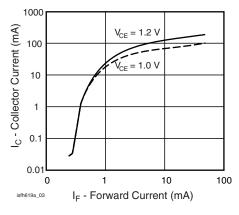
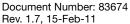


Fig. 2 - Collector Current (mA) vs. Forward Current (mA)



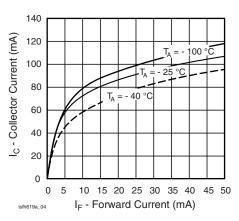
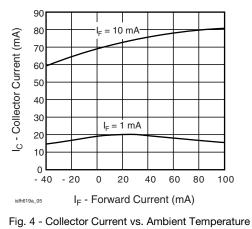


Fig. 3 - Collector Current vs. Forward Current



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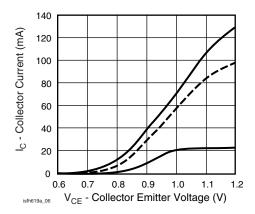


Fig. 5 - Collector Current vs. Collector Emitter Voltage

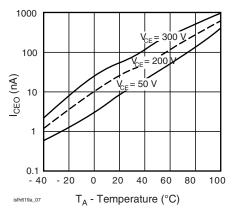


Fig. 6 - Collector Emitter Dark Current vs. Collector Emitter Voltage over Temperature

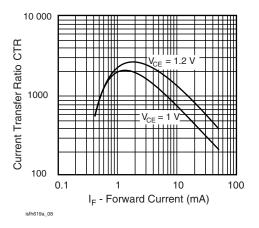


Fig. 7 - Current Transfer Ratio vs. Forward Current

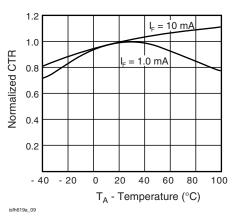


Fig. 8 - Normalized CTR vs. Temperature

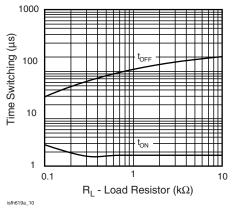


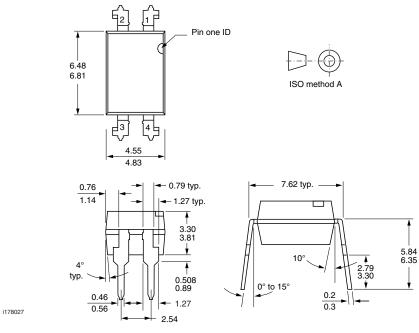
Fig. 9 - Switching Time vs. Load Resistor



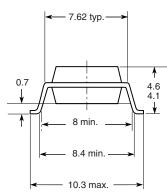
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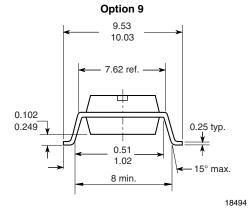
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PACKAGE DIMENSIONS in millimeters



Option 7





PACKAGE MARKING (example)



Notes

- Only option 7 reflected in the package marking.
- Tape and reel suffix (T) is not part of the package marking.

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